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April 2015

FGH20N60SFDTU_F085 600 V, 20 A Field Stop IGBT

Features

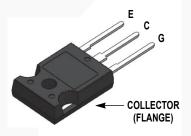
- · High Current Capability
- Low Saturation Voltage: V_{CE(sat)} = 2.2 V @ I_C = 20A
- · High Input Impedance
- · Fast Switching
- · RoHS Compliant
- · Qualified to Automotive Requirements of AEC-Q101

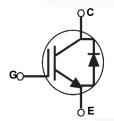
Applications

- · Automotive chargers, Converters, High Voltage Auxiliaries
- · Inverters, PFC, UPS

General Description

Using Novel Field Stop IGBT Technology, Fairchild's new series of Field Stop IGBTs offer the optimum performance for Automotive Chargers, Inverter, and other applications where low conduction and switching losses are essential.





Absolute Maximum Ratings

Symbol	Description		Ratings	Unit
V _{CES}	Collector to Emitter Voltage		600	V
V	Gate to Emitter Voltage		±20	V
V_{GES}	Transient Gate-to-Emitter Voltage		±30	V
Ic	Collector Current @ T _C = 25°C		40	A
10	Collector Current	@ T _C = 100°C	20	A
I _{CM (1)}	Pulsed Collector Current	ulsed Collector Current @ T _C = 25°C 60		A
P _D	Maximum Power Dissipation	@ T _C = 25°C	165	W
· D	Maximum Power Dissipation	@ T _C = 100°C	66	W
T _J	Operating Junction Temperature		-55 to +150	°C
T _{stg}	Storage Temperature Range		-55 to +150	°C
T _L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 second		300	°C

Notes:1: Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Unit	
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case	0.76	°C/W	
$R_{\theta JC}(Diode)$	Thermal Resistance, Junction to Case	2.51	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	40	°C/W	

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGH20N60SFDTU_F085	FGH20N60SFD	TO-247	Tube	N/A	N/A	30

Electrical Characteristics of the IGBT $T_C = 25^{\circ}$ C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	eteristics					
BV _{CES}	Collector to Emitter Breakdown Voltage	V _{GE} = 0 V, I _C = 250 μA	600	-	-	V
$\Delta BV_{CES} \ \Delta T_J$	Temperature Coefficient of Breakdown Voltage	$V_{GE} = 0 \text{ V, } I_{C} = 250 \mu\text{A}$	-	0.6	-	V/°C
I _{CES}	Collector Cut-Off Current	V _{CE} = V _{CES} , V _{GE} = 0 V	-	-	250	μА
I _{GES}	G-E Leakage Current	V _{GE} = V _{GES} , V _{CE} = 0 V	-	-	±400	nA
On Charac	teristics					
V _{GE(th)}	G-E Threshold Voltage	I _C = 250 μA, V _{CE} = V _{GE}	4.0	4.6	6.5	V
OL(III)	0	I _C = 20 A, V _{GE} = 15 V	-	2.2	2.8	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	I _C = 20 A, V _{GE} = 15 V, T _C = 125°C	-	2.4	-	V
Dynamic C	haracteristics					
C _{ies}	Input Capacitance		-	985	-	pF
C _{oes}	Output Capacitance	$V_{CE} = 30 \text{ V}, V_{GE} = 0 \text{ V},$ f = 1 MHz	-	110	-	pF
C _{res}	Reverse Transfer Capacitance	- 1 - 1 1011 12	-	40	-	pF
Switching	Characteristics					
t _{d(on)}	Turn-On Delay Time		_	13	_	ns
t _r	Rise Time		-	18	-	ns
t _{d(off)}	Turn-Off Delay Time	V _{CC} = 400 V, I _C = 20 A,	-	90	-	ns
t _f	Fall Time	$R_G = 10 \Omega$, $V_{GE} = 15 V$,	-	20	48	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 25°C	-	0.43	-	mJ
E _{off}	Turn-Off Switching Loss		-	0.13	-	mJ
E _{ts}	Total Switching Loss		-	0.56	-	mJ
t _{d(on)}	Turn-On Delay Time		-	13	-	ns
t _r	Rise Time		-	16	// -	ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 400 \text{ V, I}_{C} = 20 \text{ A,}$	-	95	-	ns
t _f	Fall Time	$R_G = 10 \Omega$, $V_{GE} = 15 V$,	-	50	- (ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 125°C	-	0.53	-	mJ
E _{off}	Turn-Off Switching Loss		-	0.24	-	mJ
E _{ts}	Total Switching Loss		-	0.77	-	mJ
Qg	Total Gate Charge			66	_	nC
Q _{ge}	Gate to Emitter Charge	V_{CE} = 400 V, I_{C} = 20 A, V_{GE} = 15 V	-	7	-	nC
Q _{gc}	Gate to Collector Charge	TYGE 10 V	-	33	-	nC

Electrical Characteristics of the Diode $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max	Unit
V _{FM} Diode Forward Voltage	Diode Forward Voltage	I _E = 10 A	T _C = 25°C	-	1.9	2.5	V
	1571	T _C = 125°C	-	1.7	-		
t _{rr}	Diode Reverse Recovery Time Diode Reverse Recovery Charge	I _r =10 A. di _r /dt = 200 A/us	$T_C = 25^{\circ}C$	-	40	-	ns
111			T _C = 125°C	-	180	-	
Q _{rr}			$T_C = 25^{\circ}C$	-	70	ı	nC
-11			$T_{\rm C} = 125^{\rm o}{\rm C}$	-	495	ı	

Figure 1. Typical Output Characteristics

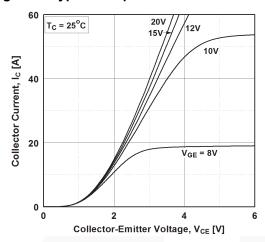


Figure 3. Typical Saturation Voltage Characteristics

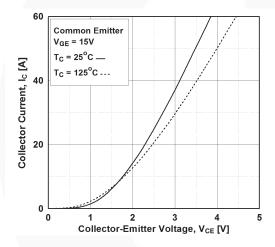


Figure 5. Saturation Voltage vs. Case
Temperature at Variant Current Level

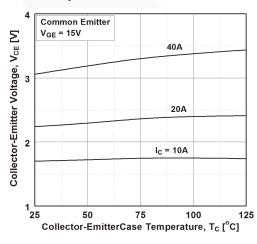


Figure 2. Typical Output Characteristics

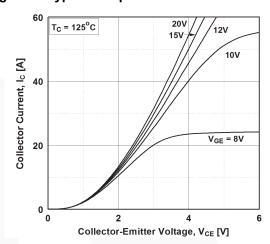


Figure 4. Transfer Characteristics

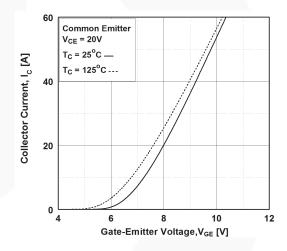


Figure 6. Saturation Voltage vs. V_{GE}

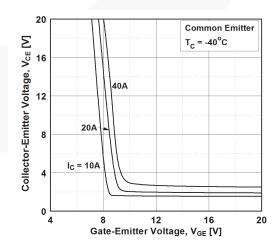


Figure 7. Saturation Voltage vs. V_{GE}

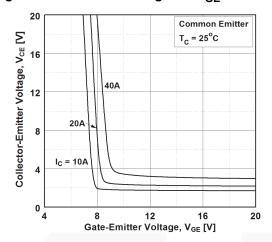


Figure 9. Capacitance Characteristics

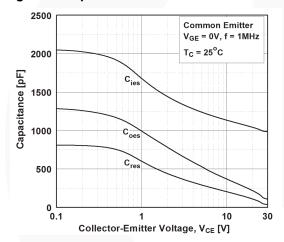


Figure 11. SOA Characteristics

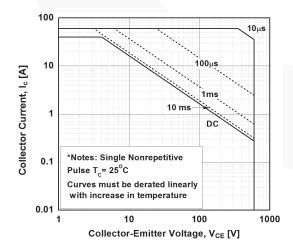


Figure 8. Saturation Voltage vs. V_{GE}

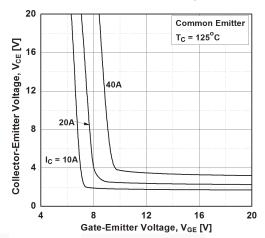


Figure 10. Gate charge Characteristics

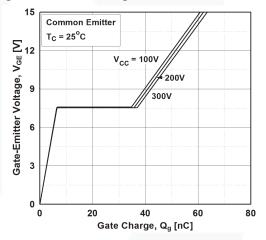


Figure 12. Turn-on Characteristics vs.
Gate Resistance

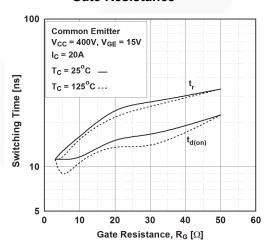


Figure 13. Turn-off Characteristics vs.
Gate Resistance

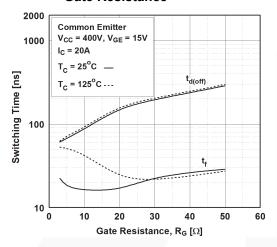


Figure 15. Turn-off Characteristics vs. Collector Current

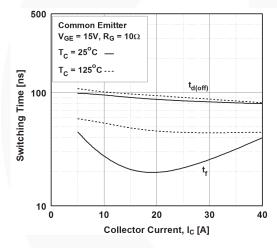


Figure 17. Switching Loss vs. Collector Current

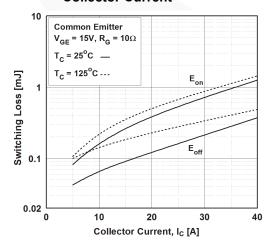


Figure 14. Turn-on Characteristics vs. Collector Current

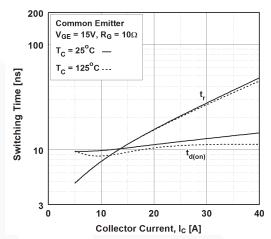


Figure 16. Switching Loss vs.
Gate Resistance

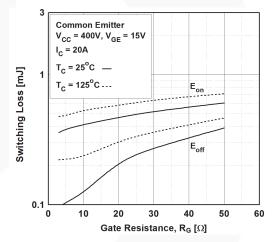


Figure 18. Turn off Switching SOA Characteristics

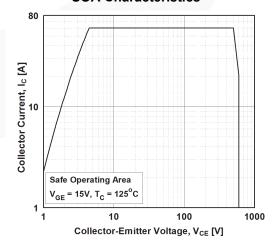


Figure 19. Forward Characteristics

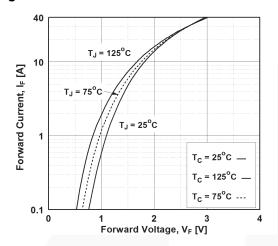


Figure 20. Reverse Current

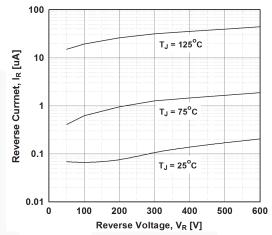


Figure 21. Stored Charge

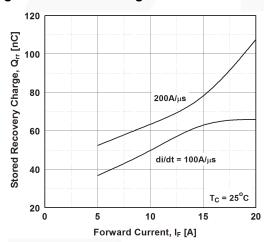


Figure 22. Reverse Recovery Time

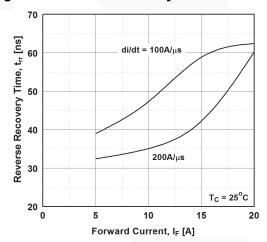
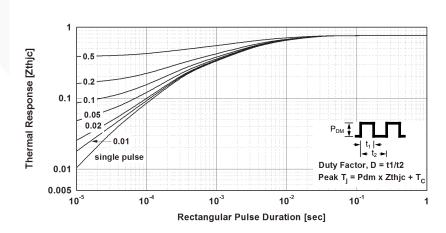
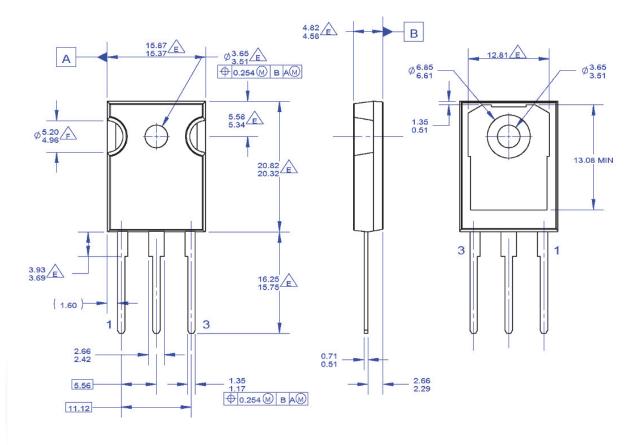


Figure 23.Transient Thermal Impedance of IGBT



Mechanical Dimensions



NOTES: UNLESS OTHERWISE SPECIFIED.

- PACKAGE REFERENCE: JEDEC TO-247,
 ISSUE E, VARIATION AB, DATED JUNE, 2004.
 DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD
- FLASH, AND TIE BAR EXTRUSIONS.
- ALL DIMENSIONS ARE IN MILLIMETERS. DRAWING CONFORMS TO ASME Y14.5 - 1994
- DOES NOT COMPLY JEDEC STANDARD VALUE
- NOTCH MAY BE SQUARE
- DRAWING FILENAME: MKT-TO247A03_REV03

Figure 24. TO-247 3L - TO-247, MOLDED, 3 LEAD, JEDEC VARIATION AB

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